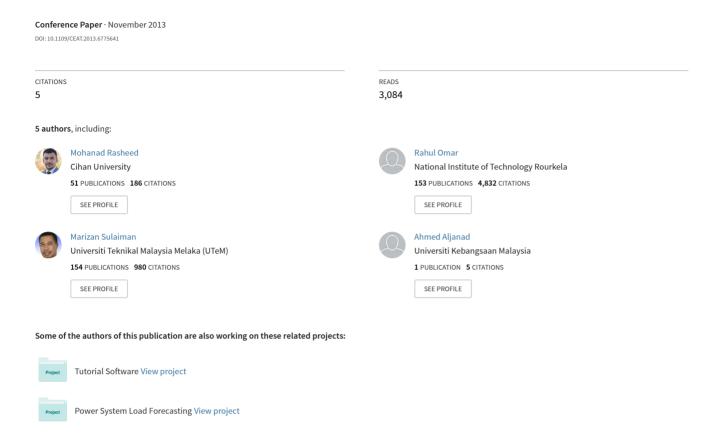
Performance studies of three-phase cascaded H-Bridge and Diode-Clamped multilevel inverters



Performance Studies of Three-Phase Cascaded H-Bridge and Diode-Clamped Multilevel inverters

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Abstract—This paper discusses a concept of two types multilevel inverters including of Cascaded H-Bridge and Diode-Clamped for harmonic reduction on high power applications. Normally, multilevel inverters can be used to reduce the harmonic problems in electrical distribution systems. These studies focused on the performance and analysis of a three phase multilevel inverters including Cascaded H-Bridge and Diode Clamp based on SPWM approaches. Based on the various simulations on nine levels of multilevel inverters, we found that the Total Harmonics Distortion for voltage (THD $_{\rm V}$) output for both multilevel inverters is decreased. It also produces lower contents based on the IEC standard.

Index Term —Multilevel inverter, diode clamped (NPC), H-Bridge inverter (CHB), SPWM.

I. INTRODUCTION

Multilevel converters provide more than two voltage levels. And general topology of the multi-level inverter can achieve a balance between the level of effort in itself, regardless of the drive control and load characteristics. The concept was introduced multi-level inverters since 1975. The applications are diverse and affect a wide field of electrical engineering from a few watts to several hundred megawatts. They are devoted to medium and high-voltage for current applications. The output quality of the current and voltage of multilevel inverter can be determined by high frequency switching techniques. The semiconductor power (e.g. GTO or IGBT high caliber) usually operate at relatively low frequencies. [1]. The structure of the nine-level inverter is most suitable, as compared to the conventional structure, since the voltages and currents output has a much lower harmonic distortion. The voltage of each switch is half and the chopping frequency is lower [2]. Multilevel inverter topologies are the Neutral-Point Clamped (NPC) inverters (or Diode-Clamped inverters), the cascaded H-bridge inverters (CHB), and the Flying Capacitor (FC) inverters (or Capacitor Clamped inverters), shown in Fig. 1 [1].

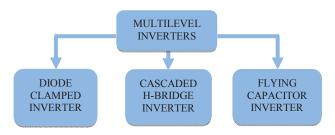


Fig.1. Multilevel Inverter Topologies.

Diode-clamped inverter has a drawback regarding the operating at complex PWM controller. However, cascaded H-bridge multilevel inverter does not this problem. Both modules have its supply the DC voltage level required, an inverter that converts DC-AC. The control structure and operation of this inverter is much more sophisticated compared to other inverters [2]. In this study, the use of GTO power will be put forward to allow higher switching frequency for harmonics reduction especially for industrial application. The (THD) for voltage and current can be calculated by using equations (1-3).

$$THD = \frac{\sqrt{\sum_{n=2}^{\infty} H_{(n)}^2}}{H_1} \tag{1}$$

Where, H_n equals to the n-th harmonics at nw₀ frequency, H_l = equals to the fundamental component.

$$h_{n} = \frac{4E}{n\pi} \sum_{k=1}^{s} \cos(n\alpha_{k})$$
(2)

$$let \ H_{(n)} = h_{n} and H_{1} = h_{1} \ _{THD} = \frac{\sqrt{\sum_{n=2}^{\infty} h_{(n)}^{2}}}{h_{1}}$$

$$THD = \frac{\sqrt{\sum_{n=2}^{\infty} (\frac{1}{n} \sum_{k=1}^{s} \cos(n\alpha_{k}))^{2}}}{\sum_{k=1}^{s} \cos(n\alpha_{k})}$$
(3)

The problem to be solved is to create a suitable modulator for controlling a voltage inverter using GTO Thyristor as switching elements for applications in high voltage and suitable at the same time to generate voltage waveforms with reduce harmonic content. Several PWM-procedures for multilevel inverters are available in [3]. Method of sinusoidal PWM (SPWM) can generate a wave with amplitude of which varies between a lower level and a higher level for a voltage by a multilevel inverter. "Phase Disposition "(PD), This method is applicable to both the NPC and the H-bridge For values of the modulation index, and the lowest total harmonic distortion In this study, we present the comparative analysis between multilevel circuits diode clamped inverter and cascaded H-Bridge inverter with (SPWM) strategies to mitigate THD nine (odd) levels. The aim of this study is to implement the carrier frequency parameter with modulation index for achieving the low harmonic distortion. The simulation was implemented by using MATLAB/SIMULINK toolbox environment.

II. MULTILEVEL INVERTER (MLI)

The multilevel inverters diagrams Fig. 2. Illustrates of the inverters have been 2-level inverter, 3-level inverter, and the N-level inverter. All the capacitors include to a voltage of $V_{\rm dc}$.

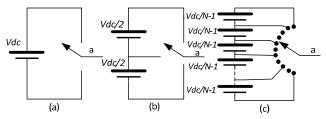


Fig. 2. The MLI diagrams of (a) 2-levels (b) 3-levels (c) N-llevels.

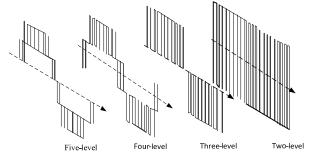


Fig. 3. Output Voltage of N-level inverter

III. MULTILEVEL INVERTERS WITH PWM METHODS

Must be a PWM signal frequency is much higher than those of the modulation signal, the fundamental frequency to generate PWM signals addressed as follows:

- 1) Sinusoidal Pulse Width Modulation (SPWM).
- 2) Space vector PWM special switching sequence of three of the upper power of the three-phase power inverter. It can be used to expand the scope of control strategies at the two higher levels

The method of pulse width modulation PWM is the most common for comparing a modulating wave (generally sinusoidal). The PWM inverters are advancing to the previous method which is square-wave inverter in the following points [6]: (i) the ability of reducing total harmonic distortion, (ii) capable of controlling the output voltage, (iii) higher power quality factor. The phenomenon of rapid and repeated switching at high speed causes the frequency of appearance of lowest order harmonic in the output voltage[4]. The techniques of the carrier PWM approaches with several variant of phase relationships for a (MLI)[5-6] are given as follows:

- 1) The carriers are in phase disposition (IPD).
- 2) Phase opposition disposition (POD). If the triangular carriers are arranged in phase opposition, then the method is phase opposition disposition (POD) that is shifted by 180° from those carriers if they are below the zero reference. This method is more efficient than the PD of the harmonic point of view low values of the modulation index.
- 3) The carrier arranged in triangular phase as Phase Disposition (PD). Each of the carriers is shifted by $2\pi/$ (N-1) radians.

A. Sinusoidal or "Sub harmonic" Natural Pulse Width Modulation (SPWM).

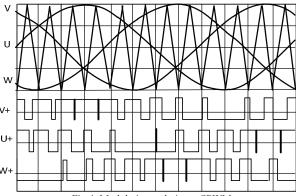


Fig 4: Modulation techniques SPWM.

In this control mode SPWM, the quality of the output voltage is being considered good if the modulation index (MI) within the range of 0 to 1.0. In case of MI is greater than 1.0, there is an anti-proportional relationship between the output quality wave and the voltage magnitude if the quality of output wave is decreased then the voltage magnitude increases. SPWM technology has its limitations regarding the maximum voltage that can be achieved, and the transfer of power. The maximum capacity of the base potential of the output waveform SPWM is the simplest of the rectangular waveform. In the case of a three-phase inverter, the proportion of the main ingredient to the line of maximum possible line voltage to a DC supply voltage is 86.6% and this indicates the use of poor the DC power supply [7].

Sinusoidal PWM (SPWM) is an effective way to reduce the lower harmonics of the system while varied output voltage. However, the low frequency harmonics content is in minimum value. The modulation approach is shown in Fig. 4.

IV. TOPOLOGIES OF MULTI LEVEL INVERTERS.

A. Topology of Neutral Point Clamped Inverter (NPC)

There is another terminology that describes the diode clamped topology which is neutral point clamped topology. The main feature of the NPC topology is that it requires only one DC source similar to two-level in high power applications, the structure is most suitable, as compared to the conventional structure. The voltages and current outputs have a much lower harmonic distortion inverter. Moreover, it provides better performance [9]. In Fig. 5, we show three-phases of nine-level diode-clamped inverter.

The nine-level can be achieved by using 16 switches; each phase is consisted of (8 switches for high leg and 8 switches for bottom leg). The three-phase shares common dc bus. The clamping diode can be used to restrict safe working level for the voltage across each capacitor. Fig. 6 depicts the 3 line-line output voltage wave for 9-level multilevel inverters. The output voltage is a 9-level staircase wave. Therefore, the *m*-level diode-clamped inverter has a (2m-1)-level output voltage and an *m*-level output phase voltage [10].

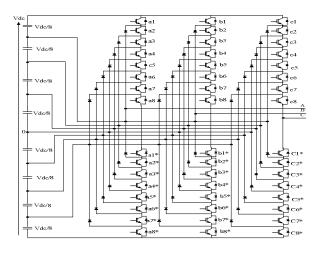


Fig. 5. Diode clamped of multilevel inverter 3-phase nine-level.

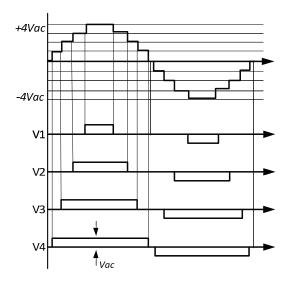


Fig.6. 9-level output voltage of multilevel inverter.

B. Topology of Cascaded H-bright Inverter (CHB)

The structure of a multilevel converter based on the series of inverters three phase H-bridge; sinusoidal wave voltage is produced by a series of connected H-bridge inverters. Each cell of the inverter is supplied by a source DC. The structure of a nine-level inverter arm cascade-type H-bridge is associated with cascade three leg three-phase inverter. The output has 2n+1 number. Total harmonic reduction can be optimized by adjusting the switching angles [11]. In comparison to diode clamped or flying capacitor, the development of inverter is cheaper. This is because the multilevel inverters very little number of components.

Fig. 7 exposes out to us the three-phase nine-level cascade H-bridge inverter. In cascaded H-bridge, each low voltage H-bridge portion has its own DC-link voltage source. Its control structure is preforming much better than previous ones [7]. This inverter is common with other inverters in having nine-level. This inverter includes 4 H-bridge inverters that are connected in one lag cascaded form. The 9-level cascaded H-bridge has been built using 16 switching devices [9].

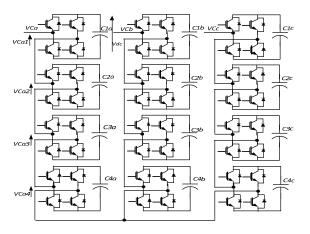


Fig. 7. Cascaded H-Bridge of multilevel inverter 3-phase nine-level.

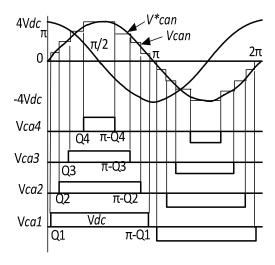


Fig. 8. 9-level Cascaded H-Bridge inverter waveforms that is shown in Fig. 7.

V. SIMULATION RESULTS.

The simulation study has performed and carried out three-phase Multilevel inverters behavior based on comparative regarding two different of a three-phase diode clamped and Cascaded H-Bridge Multilevel inverters were developed and its parameters as shown in Table 1. Fig. 9-10 show the building an Multilevel inverters model of MATLAB/SIMULINK simulation diagrams. In this simulation the constant SPWM was used. We used 8 switches GTO in diode clamped (NPC); thruster was used 48 switches GTO in Cascaded H-Bridge (CHB). The carrier frequency used in this designed is about 2500.

TABLE I. PARAMETERS OF CASCADED (CHB) AND DIODE (NPC).

Parameter	Value	
Modulation Index	M=1, 0.8	
DC Voltage Vdc =100V		
Output Frequency	Output Frequency 50 Hz	
Carrier Frequency 2500		
GTO Thyristor	8 and 48 switches,	

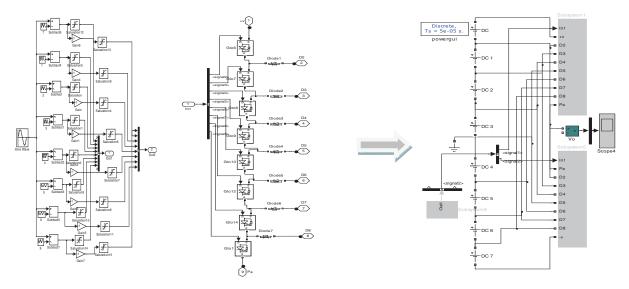


Fig. 9. Block diagram for Diode Clamped: (a) left: control signal SPWM (b) middle: switching GTO Thyristor (c) right: one lag phase block diagram Diode Clamped Inverter.

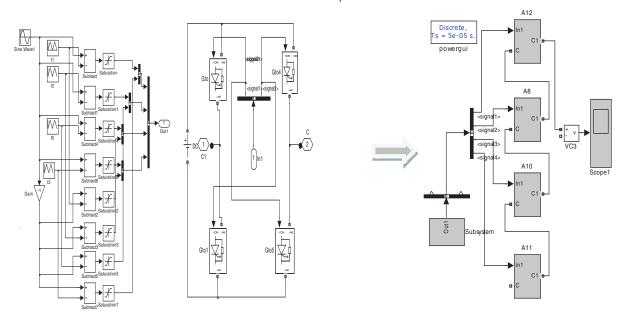


Fig.10. Block diagram for Cascade H-Bridge: (a) left: control signal SPWM (b) middle: switching GTO Thyristor (c) right: one lag phase block diagram Diode Clamped Inverter.

A. Diode clamped multilevel inverter results (NPCMLI):

The nine-level inverter waveform voltage line to neutral (NPC MLI) results is shown in Fig. 11. The modulation index is equal to 1 and output RMS voltage was equal to 315.5 V. If the modulation index decreased to 0.8 as shown in Fig. 12, the output RMS voltage was equal to 285.4 V. The quarter wave are 9 (n=9) for both of figures steps of number and the full wave are 18 (2n=18, n=9) of the number of steps.

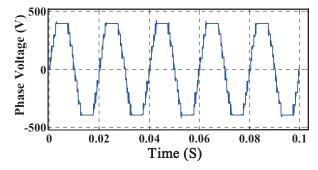


Fig.11. Phase Voltage MI=1.

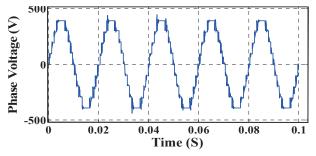
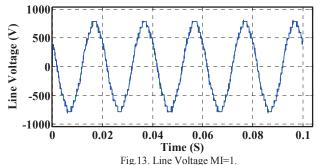


Fig.12. Phase Voltage MI=0.8.

The nine-level inverter waveform voltage line to line (NPCMLI) shows the result in Fig. 13. If modulation index is equal to 1 and output RMS voltage was equal to 542.7 V. The steps of number level quarter equal to 18 and the full wave steps level equal to 36. The modulation index decreased to 0.8 as shown in Fig. 14, output RMS voltage was equal to 492.9V.



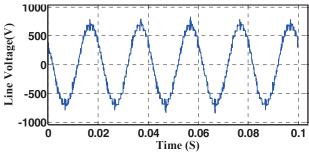


Fig.14. Line Voltage MI=0.8.

The measured MI=1 for voltage of the output diode clamped multilevel inverter the value of THD_v for voltage is around 3.9% as shown in Fig.15.

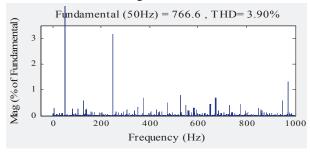


Fig.15. Harmonic Voltage M=1.

FFT analysis is the Diode clamped multilevel inverter output. The value of THD_v in Fig.16: for voltage obtained other output MI=0.8 lower than MI=1 and its value is 3.07%.

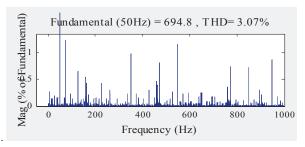


Fig.16 Harmonic Voltage M=0.8.

B. Cascaded H-Bridge multilevel inverter results (CHB):

The nine-level inverter waveform voltage lines to neutral (CHBMLI) shows the result in Fig. 17. If modulation index is equal to 1, output RMS voltage was equal to 262.2 V. When the modulation index decreased to 0.8 as shown in Fig. 18, the output RMS voltage was equal to 202.8 V. The quarter wave are 9 (n=9) for both of figures steps of number and the full wave are 18 (2n=18, n=9) of the number of steps.

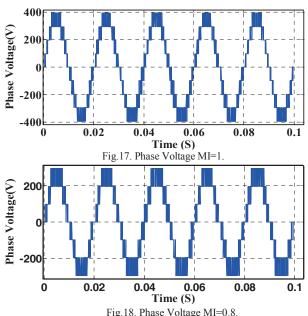
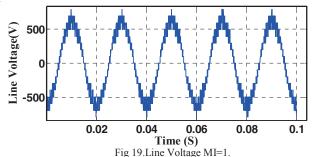


Fig. 18. Phase Voltage MI=0.8.

The nine-level inverter waveform voltage line to line (CHBMLI) shows the result in Fig. 19. With modulation index is equal to 1 and output RMS voltage was equal to 452.8 V. The steps of number level quarter equal to 18 and the full wave steps level equal to 36. The modulation index decreased to 0.8 as shown in Fig. 20, the output of RMS voltage was equal to 349.7 V.



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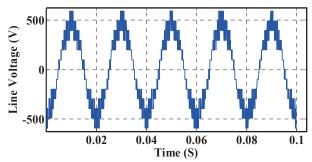


Fig 20.Line Voltage MI=0.8.

The measured MI=1 for voltage of the output Cascaded H-Bridge multilevel inverter the value of THD_{ν} for voltage is around 2.92 % as shown in Fig. 21.

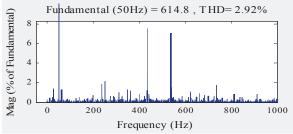


Fig 21. Harmonic Voltage M=1.

FFT analysis is the Cascaded H-Bridge multilevel inverter output. The value of $THD_{\rm v}$ show in Fig. 22: for voltage obtained other output MI=0.8 lower than MI=1 and its value is 3.58%.

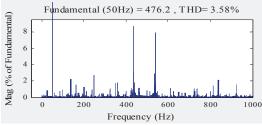


Fig.22 Harmonic Voltage M=0.8.

TABLE II. COMPARISON NINE-LEVEL OF DIODE-CLAMP AND CASCADED H-BRIDGE INVERTERS WITH DIFFERENT MODULATION INDEX (M=1, M=0.8).

M		1	0.8
Phase Voltage	Diode Clamped	315.5	285.4
	Cascaded H-Bridge	262.2	202.8
Line Voltage	Diode Clamped	542.7	492.9
	Cascaded H-Bridge	452.8	349.7
THD	Diode Clamped	3.90%.	3.07%.
	Cascaded H-Bridge	2.92%	3.58%

VII. CONCLUSION

The comparative studies between two types of multilevel inverters have been investigated. The output line voltage of the diode clamped (NPC) is slightly higher than the output line voltage of H-Bridge cascaded (CHB) multilevel inverters due to more losses available in diode clamp. However the THD_V of

both multilevel inverters are reduced and its values are following IEC standard.

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